

Project 2: 5.8 GHz High-Power RF Amplifier



ECE 6361: Microwave Design Lab

Objective

The outcome of this project is to design, assemble and test a one-stage power amplifier based on a GaN HFET transistor. The amplifier must be capable of providing 24 dB of gain across the 5.725-5.850 GHz band as well as a maximum 1dB compression point output power of 30 dBm.

Design Specifications

For this design project, the student teams will be provided the basic biasing circuit board (see resources online). You may modify the bias circuit as you see fit, but stability must be assured. You must use the brass block as is (with no other heatsinking). It is recommended that you use the following design procedure, though it is not mandatory if you have a superior alternative plan:

- 1) Use device model to predict $Z_{l,opt}$ and compare to measured data for known I_{DSQ} .
- 2) Design matching networks using for input and output using device model and/or measured source/load pull data.
- 3) Simulate, gain, k -factor, P_{1db} , P_{sat} , IMD , *etc.*, over the specified operating range. Iterate as necessary to achieve best compromise in performance. I_{DSQ} may need adjustment as well.
- 4) Assemble and test the PA.
- 5) Modify the design as necessary to achieve the best performance possible.

Please note that **PCBs and GaN HFETs** are in very limited supply. Take the following precautions when assembling and testing your PAs:

- 1) Do not bias up the device without proper terminations on input and output.
- 2) Follow **ALL** guidelines stated in the “Biasing GaN HFET” ap note.
- 3) Be sure to use appropriate **attenuators** to insure that the signal level applied to any test equipment is below the rated maximums.
- 4) Do not modify circuit **in any way** while it is operating at or near P_{sat} .
- 5) Use appropriate current limits on DC power supplies (PA should not draw more than 1A) to avoid trace burns.
- 6) Do not touch traces with fingers, tweezers, or other metal objects during RF

operation.

Below are the compliance specifications for this project:

Test Conditions:

Parameter	Symbol	Spec	Method of Compliance	Comments
Input/Output Impedance	Z_0	50 Ω	Test Condition	
Drain DC Supply Voltage	V_{DD}	24 V	Test Condition	
Gate DC Supply Voltage	V_{GG}	0 to -5 V	Test Condition	(adjusted to set I_{DSQ})
Frequency Range	f_0	5.725 -5.850 MHz	Test Condition	

Test Parameters and Specifications:

Small Signal Gain	G	24 dB	Test	Minimum at -10 dBm input
Power Output at 1 dB Gain Compression	P_{1dB}	30 dBm	Test	Minimum
Power Added Efficiency at P_{sat}	η_{added}	50%	Test	Minimum, P_{sat} defined as P_{out} @ 3 dB gain compression
Gate DC Supply Current	I_G	10 mA	Test	Maximum At $P_{out} = P_{sat}$
Input Return Loss	$ S_{11} $	-10 dB	Test	Maximum
Stability	K	>1	Simulate using measured S-parameters	Unconditional for any $ \Gamma \leq 1$ from 0.1 GHz to 6 GHz
Junction Temp at P_{1dB} , $T_{amb}=25^\circ\text{C}$	T_j	125 $^\circ\text{C}$	Calculate	At $P_{out} = P_{sat}$
Mean-time-to-failure	$MTTF$	$5 \cdot 10^8$ hrs	Calculate	At $P_{out} = P_{sat}$

Grading

Grading for the student teams is based on three parts:

1. **Written Report** – The base score of this project will be based on the written documentation of the group’s project design and implementation. Key grading points for good design documentation:
 - a. Technical Correctness
 - b. Thorough Design Methodology
 - c. Clear, *Concise* Writing
 - d. Professional Content

e. References

Design documentation should strive for succinct repeatability. All design documentation must include a bill of materials.

2. **Compliance Test** – Each team must demonstrate to the course instructor that their final device complies with the project specifications. Various project score deductions will be assessed to a team depending on how far “out-of-spec” a final device performs. Compliance may only occur immediately after a scheduled lecture.
3. **Peer Evaluation Forms** – Download the peer evaluation forms from the course site and fill them out for each team member. Various project score adjustments may be assessed to a team depending on peer-assessment of individual team member effort. Form feedback is kept confidential.